DM74ALS10A Triple 3-Input NAND Gate

FAIRCHILD

SEMICONDUCTOR

DM74ALS10A **Triple 3-Input NAND Gate**

General Description

This device contains three independent gates, each of which performs the logic NAND function.

Features

- Switching specifications at 50 pF
- Switching specifications guaranteed over full temperature and $V_{\mbox{CC}}$ range

September 1986

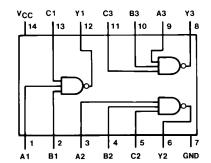
Revised February 2000

- Advanced oxide-isolated, ion-implanted Schottky TTL process
- Functionally and pin for pin compatible with Schottky and low power Schottky TTL counterpart
- Improved AC performance over Schottky and low power Schottky counterparts

Ordering Code:

Order Number	Package Number	Package Description		
DM74ALS10AM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow		
DM74ALS10ASJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide		
DM74ALS10AN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide		
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code				

Connection Diagram



Function Table

 $Y = \overline{ABC}$

	Inputs	Output	
Α	В	С	Y
Х	Х	L	Н
Х	L	х	н
L	х	х	н
н	н	н	L

H = HIGH Logic Level

L = LOW Logic Level X = Either LOW or HIGH Logic Level

Absolute Maximum Ratings(Note 1)

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	$0^{\circ}C$ to $+70^{\circ}C$
Storage Temperature Range	$-65^{\circ}C$ to $+150^{\circ}C$
Typical θ_{JA}	
N Package	86.5°C/W
M Package	116.0°C/W

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	Min	Nom	Max	Units
V _{CC}	Supply Voltage	4.5	5	5.5	V
VIH	HIGH Level Input Voltage	2			V
V _{IL}	LOW Level Input Voltage			0.8	V
он	HIGH Level Output Current			-0.4	mA
lol	LOW Level Output Current			8	mA
T _A	Free Air Operating Temperature	0		70	°C

Electrical Characteristics

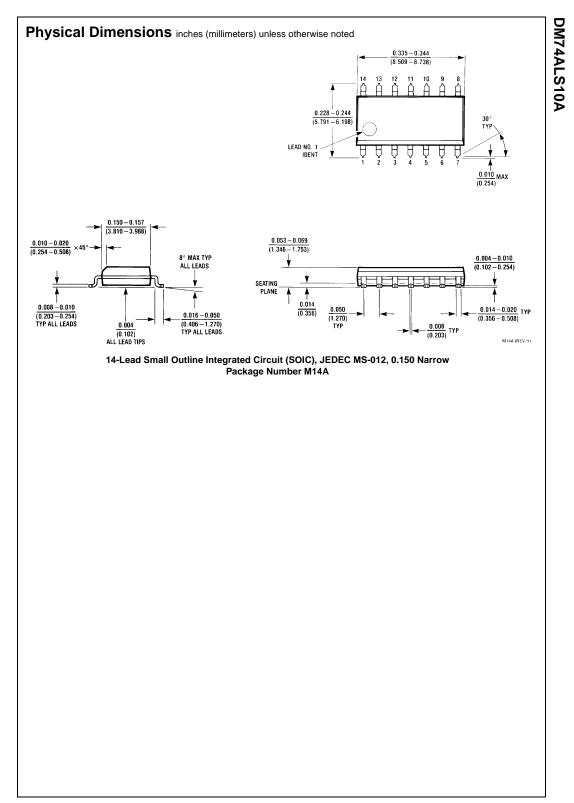
over recommended operating free air temperature range. All typical values are measured at V_{CC} = 5V, T_A = 25°C.

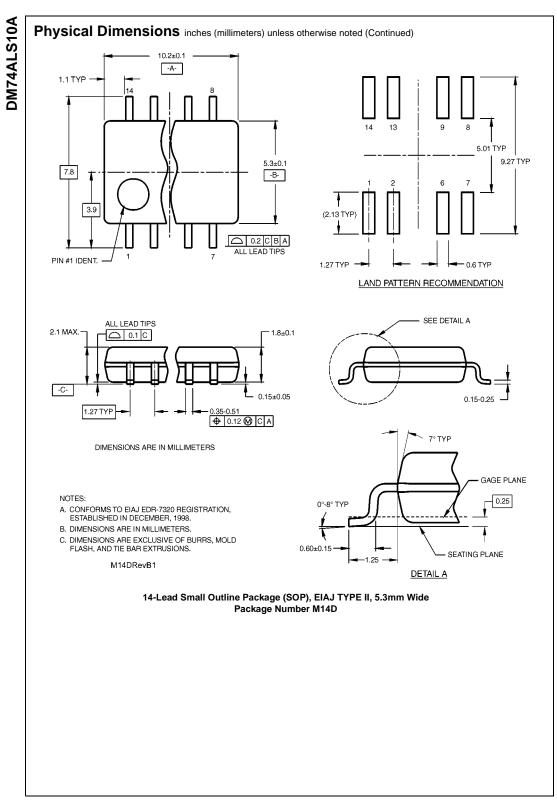
Symbol	Parameter	Conditions		Min	Тур	Max	Units
V _{IK}	Input Clamp Voltage	$V_{CC} = 4.5V, I_I = -18 \text{ mA}$				-1.5	V
V _{OH}	HIGH Level	I _{OH} = -0.4 mA		V a			V
	Output Voltage	$V_{CC} = 4.5V$ to 5.5V		V _{CC} – 2			v
V _{OL}	LOW Level	$V_{CC} = 4.5V$	$I_{OL} = 4 \text{ mA}$		0.25	0.4	V
	Output Voltage		$I_{OL} = 8 \text{ mA}$		0.35	0.5	V
II.	Input Current @ Max	$V_{CC} = 5.5V, V_{H} = 7V$				0.1	mA
	Input Voltage	$v_{CC} = 5.5 v, v_{IH} = 7 v$				0.1	ША
I _{IH}	HIGH Level Input Current	$V_{CC} = 5.5V, V_{IH} = 2.7V$				20	μA
IIL	LOW Level Input Current	$V_{CC} = 5.5V, V_{IL} = 0.4V$				-0.1	mA
I _O	Output Drive Current	$V_{CC} = 5.5V$	$V_0 = 2.25V$	-30		-112	mA
I _{CC}	Supply Current	$V_{CC} = 5.5V$	Outputs HIGH		0.32	0.6	mA
			Outputs LOW		1.7	2.4	mA

Switching Characteristics

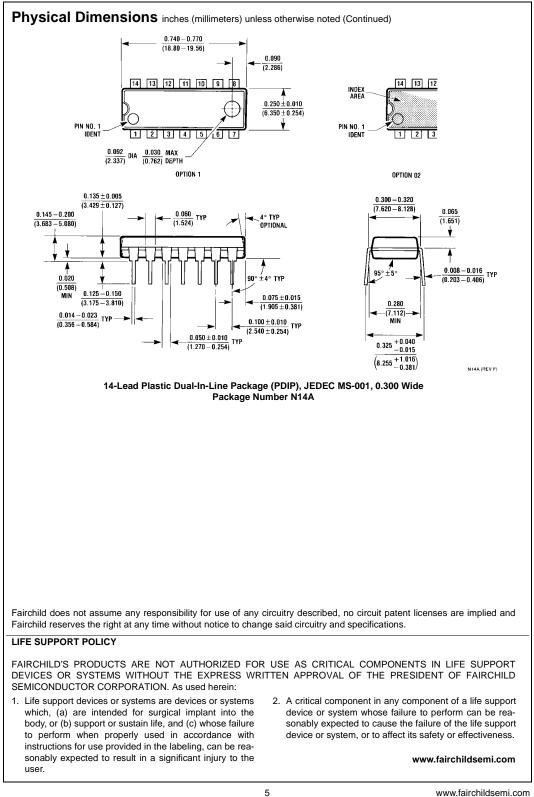
Symbol	Parameter	Conditions	Min	Max	Units
t _{PLH}	Propagation Delay Time	$V_{CC} = 4.5V$ to 5.5V	2	11	ns
	LOW-to-HIGH Level Output	$R_L = 500\Omega$			
t _{PHL}	Propagation Delay Time	$C_L = 50 \text{ pF}$	2	10	ns
	HIGH-to-LOW Level Output		2		

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